

DTB114GK

PNP -500mA -50V Digital Transistors (Bias Resistor Built-in Transistors) Datasheet

Parameter	Value
V <sub>CEO</sub>	-50V
I <sub>C</sub>	-500mA
R	$10 k\Omega$

# Features

- 1) Built-In Biasing Resistors
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Complementary NPN Types :DTD114GK
- 5) Lead Free/RoHS Compliant.

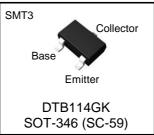
# Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

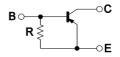
# Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTB114GK	SMT3	2928	T146	180	8	3,000	L14

#### Outline



# Inner circuit



# ●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	I <sub>C</sub>	-500	mA
Collector Power dissipation	$P_d^{*2}$	200	mW
Junction temperature	Т <sub>ј</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

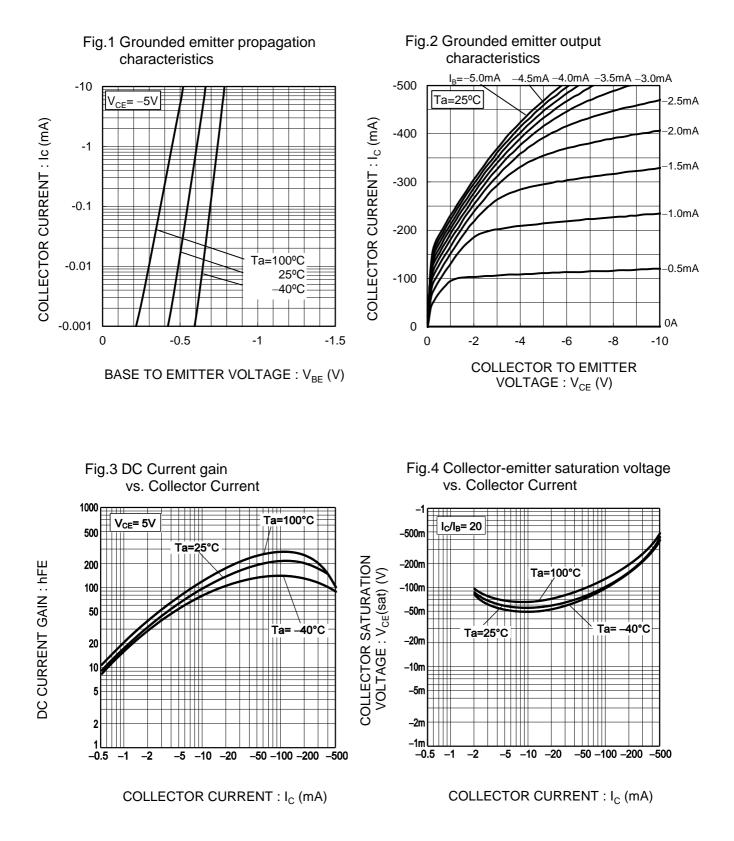
# •Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	$BV_{CBO}$	$I_C = -50 \mu A$	-50	-	-	V
Collector-emitter breakdown voltage	$BV_{CEO}$	I <sub>C</sub> = -1mA	-50	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	I <sub>E</sub> = -720μA	-5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50V$	-	-	-0.5	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -4V$	-300	-	-580	μA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> / I <sub>B</sub> = -50mA / -2.5mA	-	-	-0.3	V
DC current gain	h <sub>FE</sub>	$V_{CE}$ = -5V , I <sub>C</sub> = -50mA	56	-	-	-
Emitter-base resistance	R	-	7	10	13	kΩ
Transition frequency	f <sub>T</sub> *1	V <sub>CE</sub> = -10V, I <sub>E</sub> = 50mA, f = 100MHz	-	200	-	MHz

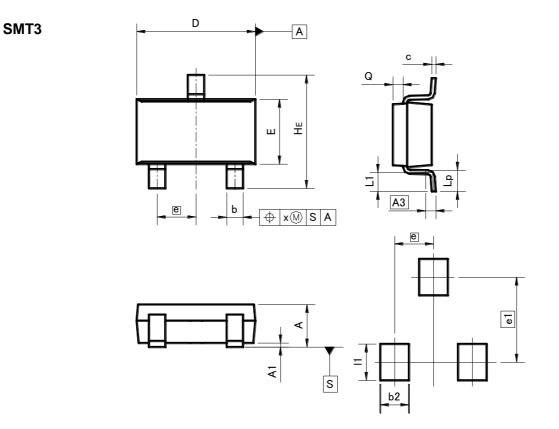
\*1 Characteristics of built-in transistor

\*2 Each terminal mounted on a reference footprint

# •Electrical characteristic curves(Ta = 25°C)



# •Dimensions (Unit : mm)



#### Patterm of terminal position areas

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	-	0.051
A1	0.00	0.10	0	0.004
A3	0.3	25	0.0	01
b	0.35	0.50	0.014	0.02
с	0.09	0.25	0.004	0.01
D	2.80	3.00	0.11	0.118
Ш	1.50	1.80	0.059	0.071
е	0.9	95	0.0	04
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
х	-	0.10	_	0.004
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	2.10		0.08		
b2		0.60	-	0.024	
1	-	0.90	-	0.035	

Dimension in mm/inches

	Notes
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